Dislocation/hydrogen interaction mechanisms in hydried nanocrystalline palladium films

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The nanoscale plasticity mechanisms activated during hydriding cycles in sputtered nanocrystalline Pd films have been investigated ex-situ using advanced transmission electron microscopy techniques. The internal stress developing within the films during hydriding has been monitored in-situ. Results showed that in Pd films hydried to β-phase, local plasticity was mainly controlled by dislocation activity in spite of the small grain size. Changes of the grain size distribution and the crystallographic texture have not been observed. In contrast, significant microstructural changes were not observed in Pd films hydrided to α-phase. Moreover, the effect of hydrogen loading on the nature and density of dislocations has been investigated using aberation-corrected TEM. Surprisingly, a high density of shear type stacking faults has been observed after dehydriding, indicating a significant effect of hydrogen on the nucleation energy barriers of Shockley partial dislocations. Ab-initio calculations of the effect of hydrogen on the intrinsic stable and unstable stacking fault energies of palladium confirm the experimental observations.

1. Introduction

Owing to its fast and reversible hydriding kinetics, palladium (Pd) is an ideal model system to study hydrogen purification and sensing applications. This is essential for hydrogen energy technology, one of the cleanest alternative to fossil fuels [1,2]. Pd has a high sensitivity and selectivity with respect to hydrogen and can release hydrogen at room temperature [2].

Recently, nanocrystalline (nc) Pd thin films have been widely used in hydrogen applications because of large surface and sub-surface site densities and of the presence of a high fraction of grain boundaries (GBs) which can facilitate the hydriding process [2,3]. These layers must be thin enough to ensure high hydrogen permeability while remaining mechanically stable [4]. The crystalline structure of Pd is a face centered cubic (fcc) lattice, also referred to as the α-phase, in which interstitial hydrogen atoms occupy part of the octahedral sites. During hydriding, as long as the H/Pd ratio stays below $\alpha_{SS_{\text{max}}} \approx 0.02$ (atomic ratio) at room temperature, the fcc α-Pd lattice parameter can expand from 3.889 Å to 3.895 Å. When H/Pd ratio reaches 0.02 a so-called β-phase appears with a lattice constant near 4.025 Å, and again an fcc structure. The two phases coexist up to a ratio H/Pd $\beta_{SS_{\text{min}}} \approx 0.58$ at which the α-phase entirely disappears. The initial volume of the Pd structure expands by about 10% when the H/Pd ratio reaches about 0.5. This dilatation can generate extremely large overall compressive stresses if the deformation is impeded by a mechanical constraint imposed to the material, such as in the case of a film lying on a thick substrate. If the material is unconstrained, it can still undergo large local stress variation if the transformation does not take place homogeneously. The large local or overall stress can induce severe local or global plastic deformation, respectively [2–8]. It was first

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shown by Wise et al. [9] that coarse-grained Pd after being sub- jected to a hydriding/dehydriding cycle contains a large dislocation density which is comparable with the dislocation density of a heavy cold-worked Pd [9,10]. Flanagan et al. [11] also reported that plastic deformation occurs both during hydriding and dehydriding in Pd which leads to an increase of the dislocation density. It has also been shown by transmission electron microscopy (TEM) results that after cold-working Pd, dislocations are arranged in cell walls with only a few dislocations within the cells, but when dislocations are created by a hydriding/dehydriding cycle, they are distributed more uniformly and it is difficult to discern a cell structure [9,12].

Robertson et al. also intensively investigated the mechanisms of hydrogen-dislocation interactions using environmental TEM for stainless steel [13], Ti [14,15] and pure Al [16]. They reported that hydrogen decreases the stacking fault energy in 310s stainless steel (SFE) and enhances the dislocation mobility (the movement of dislocations occurred at a lower applied stress). They interpreted these results by a shielding of the elastic interactions between defects (dislocation–dislocation and dislocation-pinning points). They have also investigated the separation distance between dislocations in a pileup during H absorption/desorption in pure Al. The results showed the reversible movement of dislocations in a pileup after an absorption/desorption cycle coherently with elastic shield- ing in the absence of solute pinning effects in high purity Al. Several other experimental studies have been dedicated to the study of the effect of hydrogen on the macrostructure and mechanical properties of bulk coarse-grained Pd such as the evolution of dislocation density and hardening after hydriding [17–21]. The nanoindentation experiments on coarse-grained Pd showed that local hardness is increased by 50% after hydriding the Pd to β-phase [19]. However, in depth experimental investigations on the elementary plasticity mechanisms activated in nc Pd films under hydrogen loading are still missing in the literature. Because of the complexity of the microstructure of nc metals, the microstructural changes associated to the effect of hydrogen loading may strongly differ from coarse-grained metals. Indeed, in nc metals, depending on the grain size and the local stress, the nucleation of leading partial dislocations from GBs and twinning can be favored over the formation of full lattice dislocations even in high SFE metals [22]. Furthermore, GB processes such as grain growth and grain rotation can be activated due to the increase of the local or overall stress during hydriding [23]. Another unexplored aspect concerns the experimental investigation of the nanoscale mechanisms controlling the dislo- cation/hydrogen interactions in Pd. Only a few investigations based on numerical simulations have recently tackled these questions but on other metallic materials such as nickel (Ni), aluminum (Al) and α-iron (Fe) [24–26]. Lu et al. [27] performed ab-initio calculations and found that both unstable and stable SFE in Al decrease by 50% when hydrogen atoms occupy the octahedral sites of fcc Al. Simi- larly, Taketomi et al. [28] showed through molecular statics simu- lations that the stable SFE decreases with increasing hydrogen concentration in α-Fe. Wen et al. [29] also investigated the effect of hydrogen on the dissociation of screw dislocations in Ni using the embedded-atom method, and showed that the stacking fault width of screw dislocations increases with increasing hydrogen concen- tration. Tang et al. [25] reported that the increase of the hydrogen concentration in Ni decreases the stable SFE due to the resulting negative binding energy of hydrogen to the SF, while the unstable SFE increases with increasing hydrogen concentration.

However, direct experimental evidences on the effect of hydrogen on the nucleation energy barriers of partial dislocations in fcc metals are still absent in the literature. Finally, there is no doubt that the accumulation of irreversible microstructural changes during hydriding cycles on nc Pd films can alter the mechanical properties of these films (i.e., ductility, hardening, creep, etc). Defects generated in hydrided nc Pd used in sensing applications can also have other effects such as shortening of a sensing cell’s lifetime, interruption of the electrical circuitry and lowering of the device’s sensing sensitivity and proficiency [30]. Therefore, it is of primary importance to uncover the elementary plasticity mechanisms activated during hydriding of nc Pd thin films.

In the present study, we have performed detailed TEM character- izations on nc Pd thin films prepared using sputter deposition and hydrided at low and high pressures for α-phase and β-phase transformation, respectively. The internal stress developing within the films during hydriding has been monitored in-situ using an original experimental setup based on the measurement of the curvature of the Pd films during hydriding [2,31]. Statistical ana- lyses of the grain size/morphology as well as the crystallographic texture have been performed using automated crystal orientation mapping in TEM (ACOM-TEM) while aberration corrected high resolution TEM (HRTEM) has been used to unravel the nature and the near-core properties of the defects generated during hydriding. The results revealed strong interaction of hydrogen with extended defects as well as a clear effect of hydrogen on the nucleation energy barriers of Shockley partial dislocations of Pd which was confirmed using ab-initio calculations. The results also provide insights into information for the validation of atomistic simulations on the interaction of hydrogen with extended defects and for better understanding of the effect of hydriding on the macroscopic me- chanical properties of nc metallic thin films.

2. Materials and methods

In the present study, 150 nm thick Pd films were sputter-deposited at room temperature with a deposition rate of 0.3 nm s⁻¹ under an argon (Ar) plasma pressure of 1.07 Pa. Hydriding cycles were performed after pumping down a vacuum chamber to base pressures better than 10⁻⁶ mbar, followed by the introduction of ultra-pure Ar/H₂ gas mixtures to instantaneously impose a desired partial pressure. The hydriding cycles were performed at partial pressure of ph₂ = 2.26 mbar for α-phase and 97.5 mbar for β-phase formation. The gas mixture was then pumped out of the chamber, resulting in a gradual decrease of the internal stress within the films due to reversible dehydriding at room temperature. A high-resolution curvature measurement setup is mounted onto the hydriding chamber and continuously detects the positions of multiple laser beams reflecting off a cantilevered sample, hence moni- toring the sample curvature in real time [31]. The change in internal stress in the Pd layer, which is the result of the restricted in-plane expansion during Pd–H interaction in the film-on-substrate geometry, can be derived from the measured changes in curvature [2,32]. After dehydriding, the system returns to ambient conditions, i.e. room temperature and atmospheric pressure. The hydrogen is released from the film and cross-sectional and plan-view TEM thin foils were prepared using Focused Ion Beam (FIB) thinning with the “lift-out” procedure. Conventional and HRTEM characterizations of the Pd films before and after hydriding were carried out using a FEI Tecnai G2 (PEG, 200 kV). A FEI Titan 80–300 “cubed” microscope with aberration correctors for imaging and probe was used to reveal the near-core properties of defects induced by the hydriding. Spatially resolved electron energy loss spectroscopy (EELS) tech- nique was also used to detect the residual hydrogen on the core of dislocations after hydriding.

The dislocation density was measured by counting extra half planes in HRTEM images. For better visualization of the extra half planes, a mask was applied on each g-vector and the corresponding Inverse Fast Fourier Transform (IFFT) was generated showing one family of planes. This procedure was used for all main spots present in the FFT pattern. Thus, the dislocation density was calculated
based on the number of extra half planes presented in all FFT images. Special precaution was taken to exclude regions exhibiting the so-called “reversal of contrast” due to changes of thickness/defocus. A series of HRTEM images from a given region were thus obtained at different defocus in order to reveal the presence of contrast reversal. Also, special attention was paid to avoid the misidentification of Moiré-effect-induced lattice image shifting as dislocations. In order to allow easy visualization of single dislocations, local g-maps were also obtained using Geometric Phase Analysis (GPA) which is an image processing technique sensitive to small displacements of the lattice fringes in HRTEM images [33]. A mask is applied in the FFT of the HRTEM image and centered on the periodicity (g-vector) of interest.

Twin boundary (TB) density was also measured using bright field (BF) and dark field (DF) micrographs. Around 60 grains for each film were included in the analysis. In order to ensure no twins were missed the sample was tilted up to ±30° along two perpendicular directions. Subsequently, BF images were taken after each 1° tilting.

The grain size distribution as well as the crystallographic texture of the Pd films were investigated by the ACOM-TEM technique using a Philips CM20 equipped with a LaB6 gun at 200 kV. This technique which uses small probe diffraction spot patterns in TEM is an effective method for mapping phase and crystal orientation and an alternative to Orientation Imaging Microscopy using Electron Backscattered Diffraction for scanning electron microscopes based on Kikuchi lines. A selected area is scanned with a small probe and the electron diffraction spot patterns are collected using an external Charge-Coupled Device camera. Off-line, every diffraction pattern is compared to the pre-calculated templates of Electron Backscattered Diffraction for scanning electron microscopes using the ACOM-TEM simulation package) [34] to measure the generalized planar fault energies (GPFEs) of Pd–H system. To describe the electron–ion interactions, the projector augmented-wave (PAW) method [35] was used. The wave functions on a plane wave basis with a maximum kinetic energy of 400 eV was also expanded. The exchange-correlation functional within the generalized gradient approximation (GGA) is based on the parametrization provided by Perdew, Wang and Ernzerhof (PBE) [36]. The magnetic moment was not taken into account in this work, as Pd-fcc and hydride PdH (NaCl-type structure) are not magnetic. To study bulk properties, 3×3×3 supercells were used. To compute the generalized SFEs, a supercell approach with a free surface along the [111] direction was employed. The slab was composed of 12 atomic layers along the z axis ([111] direction) and 1 or 4 atoms per layer, according to the hydrogen content. The slab was done between the sixth and the seventh layer. The surfaces are separated by a vacuum large enough, equivalent to eight interatomic layers, to reduce interactions between dangling bounds of the surfaces. 20×20×1 Monkhorst-Pack mesh grids [37] were then used to sample the Brillouin zone. These criteria were necessary to reach accurate values (For further details, see supplementary materials).

3. Experimental results

3.1. TEM characterizations of as-deposited nc Pd films

The ACOM-TEM technique was performed on as-deposited nc Pd film in order to measure the grain size distribution and the crystallographic texture. Fig. 1 shows the ACOM-TEM results including orientation map and crystallographic texture analysis along <100>, <110> and <111> directions which were performed on plan-view FIB sample of as-deposited Pd film. It is worth noting that the presence of more than one grain across the thickness of the TEM thin foils can affect the automated indexing of the diffraction patterns leading to severe uncertainties on the ACOM-TEM results. In the present work, the plan-view foils have been thinned using FIB to ensure that only one grain is confined through the thickness. Furthermore, in order to avoid ambiguities for the analysis of the grain size distribution, Σ3 TBs have been excluded in the ACOM-TEM measurements. The results of Fig. 1 show that the average lateral grain size in as-deposited Pd film is 61 ± 20 nm. Moreover, the analysis of the crystallographic texture in the as-deposited films reveals a sharp [111] fiber texture normal to the film surface (Fig. 1) which corresponds to the minimum surface energy of fcc metallic films.

Fig. 2(a) exhibits a BF-TEM micrograph obtained on cross-sectional FIB thin foils in as-deposited nc Pd film. The ring shaped selected area diffraction pattern (SADP) shown as inset in Fig. 2(a) reveals the expected fcc Pd crystalline structure. In this figure, a columnar morphological texture with an average elongated aspect ratio (height/lateral dimension ratio) of 3 can be observed. Moreover, growth nanotwins are observed within the grains. Some of these twins are indicated by white arrows in the BF micrograph of Fig. 2(a). Fig. 2(b) shows a HRTEM image of a growth Σ3[111] coherent TB (CTB). The local g-map shown in the upper left inset (same region in original image) reveals a few lattice dislocations in the matrix. The lower right IFFT inset in the same figure reveals one full lattice dislocation. Dissociated dislocations with SFs within the nanograins have not been observed, which is the expected consequence of the high SFE of Pd. Indeed, it has been reported in the literature that the SFE of Pd is ranging between 130 and 180 mJ/m² [38]. The presence of the few full lattice dislocations in the as-deposited films can be explained by the internal stress building up during the deposition of the films [39,40].
3.2. Internal stress evolution during hydriding of nc Pd films

In the present work, the internal stress has been monitored in-situ during hydriding based on the measurement of the curvature of the Pd films/Si substrate bilayer (see experimental section for more details). Fig. 3 shows the evolution of the internal stress as a function of time during a complete hydriding cycle of Pd films at $P_{H_2} = 2.28$ and 97.5 mbar which correspond to $\alpha$- and $\beta$-phase transformations, respectively. The internal tensile stress in the as-deposited Pd films is ~450 MPa. After inserting a gas mixture of Ar/($H_2$ 1%), the internal stress increases rapidly in the compressive direction, and gradually reaches a constant value of 120 MPa tensile stress for the $\alpha$-phase transformation (curve 1 in Fig. 3) and 920 MPa compressive stress for the $\beta$-phase transformation (curve 2 in Fig. 3). This leads to an absolute change of stress of 330 MPa and 1370 MPa, for Pd films hydried to $\alpha$- and $\beta$-phase, respectively. The gas mixture was then pumped out of the chamber after 225s and 380s for Pd films hydried to $\alpha$- and $\beta$-phase, respectively, resulting in a gradual decrease of the internal stress due to reversible dehydriding at room temperature. The role of the increase of the internal stress hydriding on the microstructural changes of the Pd films will be discussed in the following sections. Finally, TEM specimens are prepared ex-situ using FIB.

3.3. Effect of hydriding on grain size and crystallographic texture

The ACOM-TEM technique was also performed on Pd film after...
hydriding in order to investigate the effect of hydrogen loading on the grain size distribution and the crystallographic texture. Fig. 4 shows the ACOM-TEM results including orientation map and crystallographic texture analysis along <100>, <110> and <111> directions which were performed on plan-view Pd films after hydriding to $\beta$-phase. The results show that the average lateral grain size in Pd film after hydriding to $\beta$-phase slightly increases to 72 $\pm$ 20 nm in comparison with the as-deposited sample (61 $\pm$ 20 nm, see Fig. 1). However, because such increase falls within the uncertainties of the measurements, the activation of grain growth under hydrogen loading cannot be confirmed. On the other hand, the investigation of the mean grain size after hydriding to $\alpha$-phase did not show significant changes (i.e., 60 $\pm$ 5 nm).

The analysis of the crystallographic texture after hydriding to $\beta$-phase shows a sharp (111) fiber texture normal to the film surface (Fig. 4) very similar to the as-deposited Pd film. Moreover, the texture intensities along <100>, <110> and <111> directions remain remarkably constant after hydriding to $\beta$-phase. As expected, similar results were obtained in Pd films hydrided to $\alpha$-phase.

3.4. HRTEM investigation of the nc Pd films after hydriding

Fig. 5(a) shows a <110> HRTEM image in a Pd film after hydriding to $\alpha$-phase. In the upper right inset of this figure, the IFFT of g = 002 taken from the region indicated by dashed lines shows one full lattice dislocation. Note that local dissociation of the dislocation core cannot be resolved similarly to dislocations observed in the as-deposited films (Fig. 2(b)). Intrinsic or extrinsic SFs have not been observed in Pd films after hydriding to $\alpha$-phase. The local g-map shown in the bottom left inset (taken from the whole image of Fig. 5(a)) reveals a few lattice dislocations in the matrix similar to the as-deposited sample. The comparison of TB density of as-deposited (9300 $\pm$ 600 m$^{-2}$) and after hydriding to $\alpha$-phase (9460 $\pm$ 600 m$^{-2}$) is presented in the lower left inset showing the compact core of the dislocation. The local g-map (g = 002) of Fig. 5(a) is also presented in the lower left inset showing the dislocations as hot spots. (b) <110> HRTEM micrograph of $\Sigma$3(111) CTB in the Pd film hydrated to $\alpha$-phase showing the existence of a few steps along the TB.

These results can be explained by the low amount of hydrogen incorporated in the Pd films during hydriding to $\alpha$-phase leading to very limited hydrogen/defect interactions as well as the small variation of the internal stress during hydriding to $\alpha$-phase (curve 1 in Fig. 3).

Fig. 6(a) shows a HRTEM image obtained along the <110>-zone axis in a Pd film after hydriding to $\beta$-phase. In this figure, it can be seen that the dislocation density has significantly increased after hydriding compared to the as-deposited films (Fig. 2). Indeed, strong local variations of contrast due to the presence of a high density of dislocations are observed in these samples. This is confirmed in the local g-map of the left inset in Fig. 6(a). Furthermore, in contrast with CTBs observed in the as-deposited films (Fig. 2), the $\Sigma$3(111) CTBs in Fig. 6(a) have lost their coherency after hydriding to $\beta$-phase. This loss of coherency is due to the interaction of a high density of lattice dislocations with $\Sigma$3(111) CTBs inducing different types of structural irregularities such as residual sessile dislocations at the CTBs or lattice dislocations tangling in front of these boundaries.[41,42]

Dislocation densities have also been quantified in HRTEM images obtained in as-deposited Pd as well as films hydrided to $\alpha$- and $\beta$-phase as shown in Fig. 6(b). The error bars on the individual measurements were obtained by enlarging or shrinking the selected region in a single HRTEM image as long as the number of dislocations does not change, while those on the averages are standard error bars. Note that the scatter of dislocation density is caused by the local nature of individual nc grains of HRTEM images, presented as individual measures (open circles). The measured average lattice dislocation density in as-sputtered Pd film equals 6.0 $\pm$ 0.6 $\times$ 10$^{16}$/m$^{2}$. A slight increase to 6.7 $\pm$ 0.9 $\times$ 10$^{16}$/m$^{2}$ has been observed in Pd film hydrided to $\alpha$-phase (Fig. 6(b)). However, the measured lattice dislocation density in Pd film hydrided to $\beta$-phase reached 12.5 $\pm$ 0.2 $\times$ 10$^{17}$/m$^{2}$ which is almost 2 times higher than the initial density in as-deposited films in agreement with the clear loss of coherency of $\Sigma$3(111) CTBs shown in Fig. 6(a). Recently, using X-ray diffraction and Hydrogen diffusivities, Deutges et al. have reported dislocation densities ranging from 2 $\times$ 10$^{14}$ m$^{-2}$ to 14 $\times$ 10$^{14}$ m$^{-2}$ in coarse-grained bulk Pd samples subjected to hydrogen loading followed by cold-rolling[43]. The difference between these values and those reported in the present work can arise from the difference of the initial microstructure of the Pd samples originating from different processing methods.

Fig. 7 reveals the effects of hydriding into the $\beta$-phase regime on the local structure of lattice dislocations within the nanograins.

![Fig. 5](image-url) Fig. 5. (a) <110> HRTEM micrograph of a nanograin in Pd film after hydriding to $\alpha$-phase showing a full lattice dislocation. The IFFT of g = 002 from the region indicated by dashed lines is presented in the upper right inset showing the compact core of the dislocation. The local g-map (g = 002) of Fig. 5(a) is also presented in the lower left inset showing the dislocations as hot spots. (b) <110> HRTEM micrograph of $\Sigma$3(111) CTB in the Pd film hydrated to $\alpha$-phase showing the existence of a few steps along the TB.
SPDs with $b_1 = a/6 \{11\bar{2}\}$ and $b_2 = a/6 \{1\bar{1}T\}$. The measured width of the Shockley partial faulted loops in different grains of Pd hydrided to β-phase varies between 2.9 nm and 5.8 nm. It is worth mentioning that a dislocation labeled “d3” in Fig. 7(c) is forming a dipole with dislocation “d2”. Dislocation “d3” has been identified as a 60° full dislocation lying in the glide plane immediately adjacent to the plane of the SF loop. Similar defect configurations (intrinsic SF loop + dipole) have been observed in many different grains. Their origin will be discussed in the next section. It is also worth noting that the twin density after hydriding within the β-phase was equal to $9600 \pm 600 \, \mu m^{-2}$, very close to the value measured in the as-deposited films ($9300 \pm 600 \, \mu m^{-2}$).

3.5. Ab-initio calculations of the stacking fault energies

The observation of dissociated lattice dislocations and intrinsic faulted loops after hydriding in the β-phase domain provides direct experimental evidence that the presence of hydrogen changes the nucleation energy barriers of dislocations in Pd. This effect should be discussed in the content of the generalized stacking fault (GSF) energy theory. Indeed, both simulation and experimental works in the literature have confirmed that the GSF curve must be taken into consideration to describe the observed dislocation activity in nc materials [44]. Specifically, after a leading partial generates a SF, the nucleation and gliding barrier for the trailing partial is a function of the ratio of the unstable SFE ($\gamma_{usf}$) and intrinsic SFE ($\gamma_{isf}$). If this ratio is close to unity, full dislocations are favoured. Conversely, if this ratio is high, extended partial dislocations and SFs are expected within the nc grains. In the literature, the calculated GSF energy curve in Pd shows that $\gamma_{usf}/\gamma_{isf}$ is close to 1.5 [44], meaning that only full dislocations are expected instead of SFs, in agreement with the observation of full lattice dislocations in HRTEM images obtained in both as-deposited (Fig. 2(b)) and deformed nc Pd films in the literature [39,41,45]. In the present work, we quantitatively investigated, the impact in Pd of an increasing hydrogen concentration within the glide plane on the unstable SFE ($\gamma_{usf}$) and the stable SFE ($\gamma_{stf}$) using ab-initio calculations (see Supplemental Material for more details). The values of $\gamma_{usf}$ and $\gamma_{stf}$ are extracted from the GSF energy which is the energy per surface area when two blocks are rigidly shifted one on top of the other. A section of the GSF along a $<112>$ direction (glide plane $\{111\}$) is shown at Fig. 8(a).

Calculations with (resp. without) relaxation lead to $\gamma_{usf} = 205 \, mJ/m^2$ (resp. $236 \, mJ/m^2$) and $\gamma_{stf} = 136 \, mJ/m^2$ (resp. $139 \, mJ/m^2$) without hydrogen. Initially, the rigid shear (δ) is zero and hydrogen is introduced at an octahedral position (H-o). At δ = 1/6<112>, this site is geometrically transformed into a tetrahedral site (H-t) and one of the tetrahedral sites (H-t) transforms into a new octahedral site (H-o). The GSF is first calculated at 25 at.%H in the glide plane (Fig. 8(a)). Hydrogen remains stable throughout the shearing process and $\gamma_{usf}$ and $\gamma_{stf}$ increase up to 216 and 185 $mJ/m^2$, respectively. When the hydrogen is moved from H-t to H-o, $\gamma_{stf}$ drops down to 110 $mJ/m^2$, significantly lower than in pure Pd (136 $mJ/m^2$). Note that the maximum on the GSF has almost disappeared. This tendency is confirmed at 100 at.%H where no maximum is predicted (H-t curve on Fig. 8(b)). At δ = 1/6<112>, $\gamma_{usf} = 260 \, mJ/m^2$ when H is in H-t position and is drastically reduced in H-o ($\gamma_{usf} = 38 \, mJ/m^2$). The GSF is also calculated when hydrogen occupies H-t (filled pentagons) sites. The curve is almost flat and drops beyond δ = 1/12<112>. The energy $\gamma_{usf}$ is somewhere in between 140 and 260 $mJ/m^2$, depending on the onset of diffusion from H-t to H-o. We have not calculated the hydrogen diffusion barrier as a function of δ in Pd, but, in Al, it goes down significantly [46]. In this case, we expect $\gamma_{usf}$ to be similar to the pure Pd case.
4. Discussion

The ab-initio results demonstrate that $g_{usf}$ can increase in the presence of hydrogen, leading to a higher energy barrier for the formation of the trailing partial loops. This agrees with the observation of a high density of leading partial loops without the trailing partial loops after hydriding into the $b$-phase domain (Fig. 7(c)). This behaviour is further enhanced through the calculated decrease of $g_{usf}$. This decrease can be actually confirmed based on the observation of narrowly dissociated lattice dislocations after hydriding into the $b$-phase domain (Fig. 7(c)). This behaviour is further enhanced through the calculated decrease of $g_{usf}$. This decrease can be actually confirmed based on the observation of narrowly dissociated lattice dislocations after hydriding into the $b$-phase domain (Fig. 7(c)). It is important to note here that the effect of hydriding on $g_{usf}$ and $g_{isf}$ should be coupled to the internal stress building up during hydriding in order to explain the formation of SFs.

The presence of nanoscale Shockley partial faulted loops not reported in the literature in coarse-grained or nanocrystalline Pd is also an intriguing point, which requires extra discussion. Indeed, experimental observations of perfect or Shockley partial faulted loops have been rarely reported in nc materials because of the absence of Frank-Read sources within small grains [47]. In the present work, the origin of such behavior can be attributed to the $b$ nanohydrides that act as favorite sites for the nucleation of partial dislocation loops. The loops can thus play a role of debris, which can be used for a statistical analysis of the distribution of $b$ nanohydride formation in the nc grains. The stability of the SF loops after releasing the hydrogen also raises questions regarding dislocation/hydrogen interactions. Indeed, when the hydrogen is released at the end of the hydriding cycle, the intrinsic SFE should evolve towards its initial value leading to the reversible contraction of the SFs. Such phenomena should occur via the backward motion of the dislocation “d1” (Fig. 7(c)) due to the attractive stress applied by the SF (typically $\tau_{SF} = g_{isf}b = -495 $ MPa). Dislocation “d2” remains immobile because of the dipole “d2/d3” which cannot annihilate due to the presence of the SF.

A detailed investigation of the internal stress fields has been conducted, as provided in Fig. 7(d) and (d') based on details of the dislocations configuration observed in Fig. 7(c). The internal stress field induced by the dislocations (Fig. 7(d')) has been computed within the framework of linear isotropic elasticity [47]. Such calculations confirm that high attractive forces exist between the dislocation “d2” and “d3” forming the dipole. On the other hand, although the Peach Koehler force on the dislocation “d1” tends to extend the SF, the force magnitude is much smaller than the force induced by the fault on the partial segments: which is equal to $\tau_{disl} = 110 $ MPa. In this case, an extra shear stress of +385 MPa acting on the glide plane of the dislocation “d1” is required in order to counter balance the attractive force of the SF which thus explains the stability of this dislocation in the TEM thin foil after dehydriding. Moreover, in order to elucidate the role of the free surfaces on the dislocations in the TEM thin foil, image forces have been computed as well (Fig. 7(d')) using a Finite Element method [48] and a thin foil thickness of 10 nm (as measured by electron

Fig. 7. After hydriding to $b$-phase: (a) [110] HRTEM image of a Pd nano-grain with the corresponding FFT pattern revealing growth twins. Several SFs are indicated in the same figure by arrowheads. b) Enlarged IFFT showing a dissociated 60° dislocation with intrinsic SF. Burgers circuits are drawn around the partials and the SF. c) Enlarged IFFT showing a SF loop with opposite 90° SPDs. IFFT of (T11) plane and corresponding local g-map are shown in the upper right and lower left insets, respectively. d) Shear component of dislocations stress field and d’) image internal stress fields. The arrows show the glide component of the Peach-Koehler force induced by the SF, the dislocations and the image stresses.
The nanoscale plasticity mechanisms activated during hydriding in sputtered nc Pd films with growth TBs and subjected to hydriding cycles to induce both α- and β-phase transformations have been investigated ex-situ before and after hydriding cycles using conventional and advanced TEM techniques. The results can be summarized as follows:

- In Pd films hydrided to β-phase, local plasticity was mainly controlled by dislocation activity in spite of the small grain size. In contrast, significant microstructural changes were not observed in Pd films hydrided to α-phase.
- Intrinsic SFs have been observed after hydriding to β-phase indicating that the energy barrier for the nucleation of the trailing partials has been increased in the presence of hydrogen. 
- The observed stability of SFs in the FI B thin foils after dehydriding is attributed to the presence of stress heterogeneities in the small grains, typical of nc materials or the pinning of the partials bounding these defects by lattice dislocations. The presence of thermodynamically stable nanohydrides at the defects core has been excluded based on spatially resolved EELS measurements.

These results predict an important contribution of SFs and deformation twinning on the mechanical behavior of nc Pd films hydrided to β-phase when subjected to an external applied stress. Changes of intergranular plasticity mechanisms cannot be excluded because of local changes of the structure of GBs during hydrogen loading similarly to the changes of growth TBs observed experimentally in the present study. However, different scenarios for the mechanical response can be envisaged depending on the nature, the competition or the synergy of the activated mechanisms. In-situ TEM nanomechanical testing experiments on as-deposited and hydrided Pd films are on-going in order to elucidate the impact of the hydrogen induced defects on the atomistic deformation and cracking mechanisms as well as the mechanical properties of Pd films.

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Appendix A. Supplementary data

Supplementary data related to this article can be found at http://dx.doi.org/10.1016/j.actamat.2016.03.054.

References
